



P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(\Omega)$	I _D (A)		
-8	0.009 @ V _{GS} = -4.5 V	-14		
	0.011 @ V _{GS} = -2.5 V	-12		
	0.016 @ V _{GS} = -1.8 V	-10		

TrenchFET®

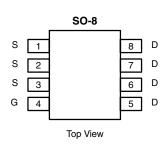
TrenchFETS

Power MOSFETS

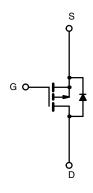
1.8-V Rated



COMPLIANT



Ordering Information: Si4465DY-T1 Si4465DY-T1-E3 (Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	-8	.,	
Gate-Source Voltage		V _{GS}	±8	v	
Continuous Drain Current (T, _I = 150°C) ^{a, b}	T _A = 25°C		-14		
Continuous Diam Current (1) = 150 C) (5)	T _A = 70°C	- d	-11	A	
Pulsed Drain Current		I _{DM}	-40	─	
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	-2.1		
Mandanian David Disabation 2 h	T _A = 25°C	D.	2.5	w	
Maximum Power Dissipation ^{a, b}	T _A = 70°C	P _D	1.6	VV	
Operating Junction and Storage Temperature Range		T _J , T _{sta}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Advisory by the Archiveta	t ≤ 10 sec	- R _{thJA}		50	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		80			

Notes

a. Surface Mounted on FR4 Board.

b. $t \le 10$ sec.

Vishay Siliconix



SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Static	<u> </u>		•	•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-0.45		-1.0	٧	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ±8 V			± 100	nA	
		$V_{DS} = -8 \text{ V}, V_{GS} = 0 \text{ V}$	_{OS} = -8 V, V _{GS} = 0 V		-1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -8 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-20			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -14 \text{ A}$		0.007	0.009		
Drain-Source On-State Resistance ^a	r _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -12 \text{ A}$		0.009	0.011	Ω	
		$V_{GS} = -1.8 \text{ V}, I_D = -10 \text{ A}$		0.012	0.016		
Forward Transconductance ^a	9fs	$V_{DS} = -10 \text{ V}, I_D = -14 \text{ A}$		60		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = -2.1 \text{ A}, V_{GS} = 0 \text{ V}$		0.7	-1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			80	120	nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = -4 \text{ V}, \ V_{GS} = -4.5 \text{ V}, \ I_D = -14 \text{ A}$		15			
Gate-Drain Charge	Q _{gd}			9			
Gate Resistance	R _G			3.3	5	Ω	
Turn-On Delay Time	t _{d(on)}			45	90	ns	
Rise Time	t _r	$V_{DD} = -4 \text{ V}, R_L = 4 \Omega$		55	110		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -1$ Å, $V_{GEN} = -4.5$ V, $R_G = 6 \Omega$		380	760		
Fall Time	t _f			190	380		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.1 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		80	120		

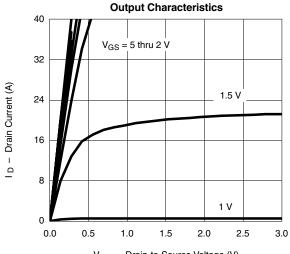
Notes a. Pulse test; pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$. b. Guaranteed by design, not subject to production testing.



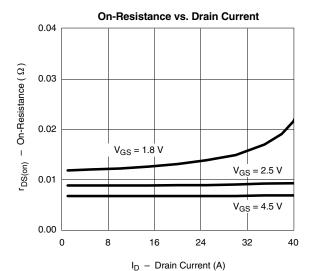


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TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

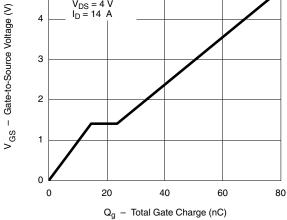


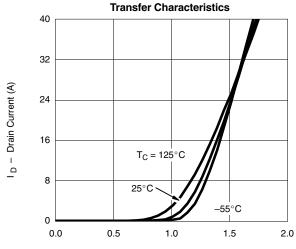




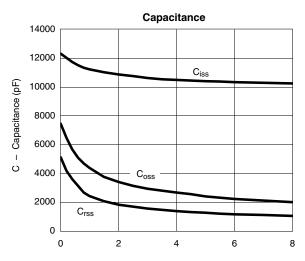
 $V_{DS} = 4 V$ $I_D = 14 A$

Gate Charge

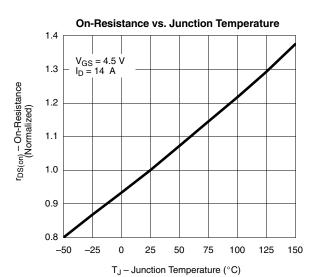




V_{GS} - Gate-to-Source Voltage (V)



V_{DS} - Drain-to-Source Voltage (V)

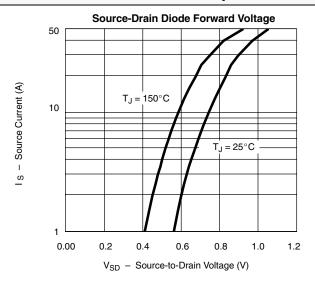


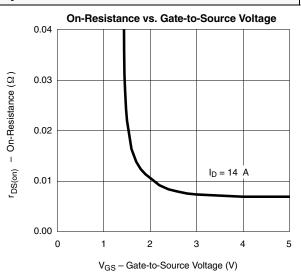
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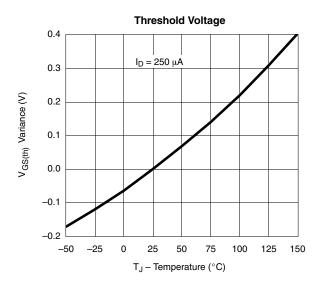
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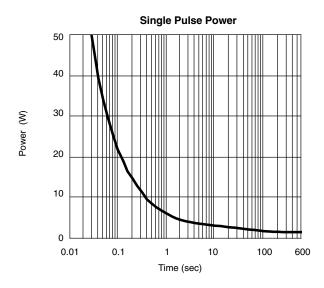


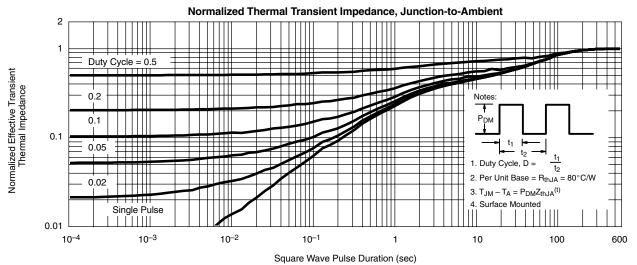
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)











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